June12-15, 2017

Berkeley, CA

Session	Speakers	Company		Start	Finish	Title		
	June 12, 2017 Instructors 8:30 17:00 EUVL Short Course							
	Instructors			8.50	17.00			
		June	e 13, 20	017				
	Facility Tour 15:00 17:00							
	Registration, Speak	er Prep and Recepti	on	17:00	18:30			
luno 14, 2017								
June 14, 2017								
	VB/All	EUV Litho	0:20	8:00	8:20	Welcome and Introduction		
Session 1: Keynote -1	P1 Obert Wood	GlobalFoundries	0:40	8:20	9:00	EUV: current status & remaining challenges		
	P3 Britt Turkott	Intel	0:40	9:00	9:40	EUV Lithography for HVM		
	Break		0:20	9:40	10:00			
						EUV Mask Economics: Impact of mask costs on		
Session 2: Mask	P33 Bryan Kasprowicz	Photronics	0:20	10:00	10:20	patterning strategy		
	P39 Adrian Devasahaya	m Veeco	0:20	10:20	10:40	Reduction of Large Killer Defects in EUV Mask Blanks		
						New SUBARU EUVL R&D Activities and EUV Mask		
	P34 Takeo Watanabe	Univ. of Hyogo	0:20	10:40	11:00	Defect Inspection		
						Anamorphic Imaging: Emulating Future Nodes of EUV		
	P38 Marcus Benk	LBL	0:20	11:00	11:20	Lithography on the SHARP Microscope		
						Improved inspection ability of Coherent Scattering		
	P31 YoungWoong Kim	Hanyang	0:20	11:20	11:40	Microscopy by applying Ptychography		
	P32 Patrick Helfenstein	PSI	0:20	11:40	12:00	RESCAN - A standalone tool for EUV mask defect		
						Rigorous 3D electromagnetic simulation of ultrahigh		
	P37 Stuart Sherwin	LBL				efficiency EUV contact-hole printing with Chromeless		
	Lunch		1:00	12:20	13:20			
						kW-class picosecond thin-disk pre-pulse laser Perla for		
Session 3: Source-1	P11 Akira Endo	HILASE	0:20	13:20	13:40	efficient EUV generation		
						Scalability of CO_2 amplifiers to generate stable > 500W		
	P12 Yasui Koji	Mitsubishi	0:20	13:40	14:00	extreme ultraviolet (EUV) beams		
	P13 Howard Scott	LLNL	0:20	14:00	14:20	Simulating EUV Production - an Overview of the		
	P14 Oscar Versolato	ARCNL	0:20	14:20	14:40	Short-pulsed Nd:YAG laser interaction with tin micro-		



		Break		0:20	14:40	15:00	
							Next Generation Source Power Requirements: What
Session 4: Source-2	P15	5 Erik Hosler	GF	0:20	15:00	15:20	will we need at the 3 nm node and beyond?
							A Compact Linac-Driven EUV Light Source utilizing a
	P16	5 Filippos Toufexis	Standford	0:20	15:20	15:40	Short-Period Microwave-Driven Undulator
							Concept for 1kW EUV Source for Lithography Based on
	P17	Michael Feser	Lyncean	0:20	15:40	16:00	FEL Emission in Compact Storage Ring
							Challenges to realize the EUV-FEL high power light
	P18	3 Hiroshi Kawata	KEK	0:20	16:00	16:20	source - Present status on the EUV-FEL R&D activities -
			Post	er Pap	ers		
					17:00	18:00	
							Large Collector Mirror Reflectometer for the High
Session 5: Poster Papers	P25	5 Takeo Watanabe	Univ. of Hyogo				Power EUV Light Source Achievement
	P35	5 Aamod Shankar	LBL				Measuring aberrations with mask roughness
							Impact of tool design on defect detection sensitivity
	P36	5 Yow-Gwo Wang	LBL				for EUV actinic blank inspection.
							Variable Separation Method for Three-dimensional
) Xiangzhao Wang	SIOM				EUVL mask diffraction simulation
	P51	Fallica Roberto Alfio	PSI				Estimation of lithographically-relevant secondary
			line of the sec				EUV Lithography Research and Development Activities
	P52	2 Takeo Watanabe	Univ. of Hyogo				at University of Hyogo
		Additional Poster Pa	apers to be Announ	ced			
			Thursday,	, June 1	15, 201	.7	
		Vivek Bakshi	Announcemnts	0:10	8:00	8:10	
							Tabletop Coherent EUV Sources and Applications: Full
.	_				_	-	Field Sub-Wavelength Imaging at 13.5nm and
Session 6: Keynote -2	Ρ4	Margaret Murnane	Univ. of Colorado	0:40	8:10	8:50	Materials Metrology
					0		High Power HVM LPP-EUV Source with Long Collector
	P2	Hakaru Mizoguchi	Gigaphoton	0:40	8:50	9:30	Mirror Lifetime



			EUV Lithography: Progress in LPP Source Power Scaling
	P5 Igor Fomenkov	Cymer	0:40 9:30 10:10 and Availability
	Break		0:20 10:10 10:30
Session 7: Optics and			
Contamination	P21 Norbert Bowerings	TNO	EUV optics life time research, past, present and future 0:30 10:30 11:00
			The future of EUV lithography: enabling Moore's law in
	P22 Jan van Schoot	ASML	0:20 11:00 11:20 the next decade
	P23 Jack Liddle	Zeiss	0:20 11:20 11:40 Latest developments in EUV optics
	P24 Ladislav Pina	RITE	0:20 11:40 12:00 EUV/SXR Optics and Metrology Development at RITE
	Lunch		1:00 12:00 13:00
Session 8: Resist and			
Patterning -1	P47 Greg McIntyre	IMEC	0:20 13:00 13:20 EUV developments at imec
			Reactivity of Metal Oxalate EUV Resists as a Function
	P41 Greg Denbeaux	Ualbany	0:20 13:20 13:40 of the Central Metal
	P43 Yoshi Hishiro	JSR	0:20 13:40 14:00 Novel EUV resist development for sub-7 nm node
	P50 Jason Stowers	Inpria	0:20 14:00 14:20 Metal Oxide Photoresists: Breaking Paradigms in EUV
			Fundamental aspects of PSCAR breaking RLS trade-off
	P46 Seiichi Tagawa	Osaka	0:20 14:20 14:40 and photon shot noise comparing with CAR and non-
		Break	0:20 14:40 15:00
Session 9: Resist and			Towards Real-Time Analysis of Morphologies using
Patterning -2	P42 Alex Hexemer	LBL	0:20 15:00 15:20 Scattering
			Extreme ultraviolet induced chemical reactions in
	P44 Sonia Ortega	ARCNL	0:20 15:20 15:40 photoresists and model systems
			Fundamentals of X-Ray Excitation and Relaxation in
	P45 Frank Ogletree	LBL	0:20 15:40 16:00 EUV Resists (Tentative Title)
	P48 Dan Slaughter	LBL	0:20 16:00 16:20 Fundamental aspects of low energy electron driven
	P70 Vivek Bakshi	EUV Litho	0:20 16:20 16:40 Meeting Summary
			16:45 Depart for Dinner Cruise

